

# Advance Technical Information

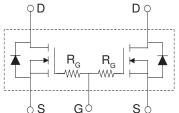
# TrenchMV<sup>™</sup> Power MOSFETs Common-Gate Pair

### IXTL2x220N075T

# $V_{DSS} = 75 V$ $I_{D25} = 2x120 A$ $R_{DS(on)} \le 5.5 m\Omega$

## (Electrically Isolated Back Surface)

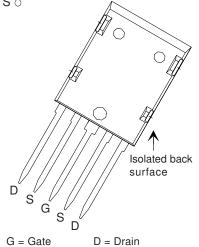
N-Channel Enhancement Mode Avalanche Rated



ISOPLUS i5-Pak™ (IXTL)

Symbol	<b>Test Conditions</b>	Maximum F	Ratings	
V <sub>DSS</sub> V <sub>DGR</sub>	$T_J = 25^{\circ}\text{C to } 175^{\circ}\text{C}$ $T_J = 25^{\circ}\text{C to } 175^{\circ}\text{C}; R_{GS} = 1 \text{ M}\Omega$	75 75	V V	
V <sub>GSM</sub>	Transient	± 20	V	
I <sub>D25</sub>	T <sub>C</sub> = 25°C (Combined die total = 240 A)	120	А	
LRMS	Package Current Limit, RMS (Combined die total = 150 A)	75	Α	
I <sub>DM</sub>	$T_{\rm C} = 25^{\circ}$ C, pulse width limited by $T_{\rm JM}$	600	Α	
I <sub>AR</sub> E <sub>AS</sub>	$T_c = 25^{\circ}C$ $T_c = 25^{\circ}C$	25 1.0	A J	
dv/dt	$I_{_{S}} \leq I_{_{DM}},  di/dt \leq 100  A/\mu s,  V_{_{DD}} \leq V_{_{DSS}}$ $T_{_{J}} \leq 175^{\circ}C,  R_{_{G}} = 3.3  \Omega$	3	V/ns	
P <sub>D</sub>	T <sub>C</sub> = 25°C	150	W	
T <sub>J</sub> T <sub>JM</sub>		-55 +175 175 -55 +175	°C °C °C	
T <sub>stg</sub> T <sub>L</sub> T <sub>SOLD</sub>	1.6 mm (0.062 in.) from case for 10 s Plastic body for 10 seconds	300 260	°C °C	
V <sub>ISOL</sub>	50/60 Hz, t = 1 minute, $I_{ISOL}$ < 1 mA, RMS	2500	V	
F <sub>c</sub>	Mounting force	20120/4.525	N/lb.	
Weight		9	g	

			aracteris Typ.	eristic Values Max.		
BV <sub>DSS</sub>	$V_{GS} = 0 \text{ V}, I_{D} = 250  \mu$	A	75			V
V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_{D} = 250 \ \mu .$	A	2.0		4.0	V
I <sub>GSS</sub>	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$	V			± 200	nA
DSS	$V_{DS} = V_{DSS}$ $V_{GS} = 0 V$	T <sub>J</sub> = 150	0°C		5 250	μ <b>Α</b> μ <b>Α</b>
R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_{D} = 50 \text{ A}$	Notes 1, 2			5.5 r	nΩ



#### **Features**

S = Source

- Ultra-low On Resistance
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
- easy to drive and to protect
- 175 °C Operating Temperature

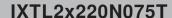
#### **Advantages**

- Easy to mount
- Space savings
- High power density

#### **Applications**

- Automotive
  - Motor Drives
  - 42V Power Bus
  - ABS Systems
- DC/DC Converters and Off-line UPS
- Primary Switch for 24V and 48V Systems
- High Current Switching Applications

All ratings and parametric values are per each MOSFET die unless otherwise specified.





Symbol	Test Conditions $(T_{_{J}}=25$	°C unless	Characteristic Values C unless otherwise specified)		
		Min.	Тур.	Max	
g <sub>fs</sub>	$V_{DS} = 10 \text{ V}; I_{D} = 60 \text{ A}, \text{ Note 1}$	75	120		S
$\mathbf{R}_{G}$			3		Ω
C <sub>iss</sub>			7700		pF
C <sub>oss</sub>	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$		1100		pF
C <sub>rss</sub>			230		pF
$\mathbf{t}_{d(on)}$			29		ns
t <sub>r</sub>	$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \text{ V}_{DSS}, I_{D} = 25 \text{ A}$		65		ns
$\mathbf{t}_{d(off)}$	$R_G = 3.3 \Omega \text{ (External)}$		55		ns
t,			47		ns
$\mathbf{Q}_{g(on)}$			165		nC
$Q_{gs}$	$V_{GS} = 10 \text{ V}, V_{DS} = 0.5 \text{ V}_{DSS}, I_{D} = 25 \text{ A}$		40		nC
$\mathbf{Q}_{gd}$			50		nC
R <sub>thJC</sub>				1.0	°C/W
R <sub>thCS</sub>			0.5		°C/W

#### Source-Drain Diode

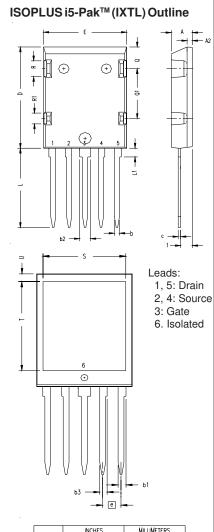
Symbol	Test Conditions	Min.	Тур.	Max.	
I <sub>s</sub>	$V_{GS} = 0 V$			220	Α
I <sub>SM</sub>	Pulse width limited by $T_{JM}$			600	Α
V <sub>SD</sub>	$I_F = 50 \text{ A}, V_{GS} = 0 \text{ V}, \text{ Note 1}$			1.0	V
t <sub>rr</sub>	$I_F = 25 \text{ A}, -di/dt = 100 \text{ A/}\mu\text{s}$		50		ns
	$V_{R} = 40 \text{ V}, V_{GS} = 0 \text{ V}$				

Notes: 1. Pulse test:  $t \le 300 \mu s$ , duty cycle d  $\le 2 \%$ ;

2. Drain and Source Kelvin contacts must be located less than 5 mm from the plastic body.

#### **ADVANCETECHNICALINFORMATION**

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.



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#### Note:

- 1. TAB 6 Electrically isolated from the other pins.
- 2. All leads and tab are tin plated.

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